

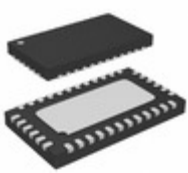

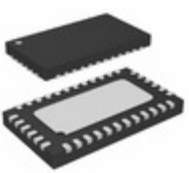





	<h2 style="color: #E67E22;">SI3454ADV-T1-E3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI3454ADV-T1-E3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET N-CH 30V 3.4A 6-TSOP
	Datenblätter:  SI3454ADV-T1-E3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 49954 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI3454ADV-T1-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 3.4A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	49954 pcs Stock
detaillierte Beschreibung	N-Channel 30V 3.4A (Ta) 1.14W (Ta) Surface Mount 6-
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A (Ta)
Rds On (Max) @ Id, Vgs	60 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI3454ADV-T1-E3TR

SI3454ADV-T1-E3 ist neu im Original, Suche SI3454ADV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3454ADV-T1-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI3454ADV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3454-B01-IM Energy Micro (Silicon Labs) IC POE PSE 4 PORT 802.3AT 38QFN</p>	 <p>SI3454ADV-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 3.4A 6-TSOP</p>	 <p>SI3454-B01-IMR Energy Micro (Silicon Labs) IC POE PSE 4 PORT 802.3AT 38QFN</p>	 <p>SI3454-KIT Energy Micro (Silicon Labs) EVAL KIT FOR SI3454 POE CTLR</p>
 <p>SI3454ADV-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 3.4A 6TSOP</p>	 <p>SI3454ADV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 3.4A 6TSOP</p>	 <p>SI3454ADV-T1 VISHAY SI3454ADV-T1 VISHAY</p>	 <p>SI3453DV-T5-GE3 VISHAY SI3453DV-T5-GE3 VISHAY</p>

heiße Teile

Mehr

SI3447BDV-T1-E3	SI3447BDV-T1-GE3	SI3447BDV-T1-GE3	SI3447BDV-TI-GE3	SI3447CDV-T1
SI3447CDV-T1-E3	SI3447CDV-T1-E3	SI3447CDV-T1-GE3	SI3447CDV-T1-GE3	SI3447DV
SI3447DV-NL	SI3447DV-T1	SI3447DV-T1-E3	SI3447DV-T1-GE3	SI3448DV
SI3448DV-T1-E3	SI3451DV-T1-E3	SI3451DV-T1-E3	SI3451DV-T1-GE3	SI3451DV-T1-GE3
SI3452DV-T1-E3	SI3453DV-T1-GE3	SI3453DV-T1-GE3	SI3453DV-T5-GE3	SI3454ADV-T1
SI3454ADV-T1-E3	SI3454ADV-T1-GE3	SI3454ADV-T1-GE3	SI3454CDV-T1-GE3	SI3454CDV-T1-GE3
SI3454DV-NL	SI3454DV-T1	SI3454DV-T1-E3	SI3455ADV-T1-E3	SI3455ADV-T1-E3
SI3455ADV-T1-GE3	SI3455ADV-T1-GE3	SI3455DV-NL	SI3455DV-T1-E3	SI3455DV-T1-GE3
SI3456-C02-GU	SI3456-E04-GU	SI3456BD-T1-E3	SI3456BDV-T1	SI3456BDV-T1-E3
SI3456BDV-T1-E3	SI3456BDV-T1-GE3	SI3456BDV-T1-GE3	SI3456CDV-T1-E3	SI3456CDV-T1-E3

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